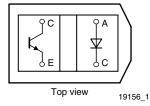


Vishay Semiconductors

# **Reflective Optical Sensor with Transistor Output**





#### **DESCRIPTION**

The TCRT5000 and TCRT5000L are reflective sensors which include an infrared emitter and phototransistor in a leaded package which blocks visible light. The package includes two mounting clips. TCRT5000L is the long lead version.

#### **FEATURES**

· Package type: leaded

• Detector type: phototransistor

• Dimensions (L x W x H in mm): 10.2 x 5.8 x 7

· Peak operating distance: 2.5 mm

 Operating range within > 20 % relative collector current: 0.2 mm to 15 mm

• Typical output current under test: I<sub>C</sub> = 1 mA

· Daylight blocking filter

• Emitter wavelength: 950 nm

· Lead (Pb)-free soldering released

 Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### **APPLICATIONS**

- · Position sensor for shaft encoder
- Detection of reflective material such as paper, IBM cards, magnetic tapes etc.
- · Limit switch for mechanical motions in VCR
- · General purpose wherever the space is limited

| PRODUCT SUMMARY |  |  |  |   |  |
|-----------------|--|--|--|---|--|
| PART NUMBER     | DISTANCE FOR MAXIMUM CTR <sub>rel</sub> (1) (mm) | DISTANCE RANGE FOR RELATIVE I <sub>out</sub> > 20 % (mm) | TYPICAL OUTPUT CURRENT UNDER TEST (2) (mA) | DAYLIGHT<br>BLOCKING FILTER<br>INTEGRATED |  |
| TCRT5000        | 2.5  | 0.2 to 15  | 1  | Yes                                       |  |
| TCRT5000L       | 2.5  | 0.2 to 15  | 1  | Yes                                       |  |

#### **Notes**

- $^{(1)}$  CTR: current transfere ratio,  $I_{out}/I_{in}$
- (2) Conditions like in table basic charactristics/sensors

| ORDERING INFORMATION |           |                            |                    |  |  |
|----------------------|-----------|----------------------------|--------------------|--|--|
| ORDERING CODE        | PACKAGING | VOLUME (1)                 | REMARKS            |  |  |
| TCRT5000             | Tube      | MOQ: 4500 pcs, 50 pcs/tube | 3.5 mm lead length |  |  |
| TCRT5000L            | Tube      | MOQ: 2400 pcs, 48 pcs/tube | 15 mm lead length  |  |  |

#### Note

(1) MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (1) |                          |                  |       |      |  |
|------------------------------|--------------------------|------------------|-------|------|--|
| PARAMETER                    | TEST CONDITION           | SYMBOL           | VALUE | UNIT |  |
| INPUT (EMITTER)              |                          |                  |       |      |  |
| Reverse voltage              |                          | V <sub>R</sub>   | 5     | V    |  |
| Forward current              |                          | I <sub>F</sub>   | 60    | mA   |  |
| Forward surge current        | $t_p \le 10 \; \mu s$    | I <sub>FSM</sub> | 3     | Α    |  |
| Power dissipation            | T <sub>amb</sub> ≤ 25 °C | P <sub>V</sub>   | 100   | mW   |  |
| Junction temperature         |                          | T <sub>j</sub>   | 100   | °C   |  |

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# **TCRT5000, TCRT5000L**

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| ABSOLUTE MAXIMUM RATINGS (1) |                                      |                  |               |      |  |
|------------------------------|--------------------------------------|------------------|---------------|------|--|
| PARAMETER                    | TEST CONDITION                       | SYMBOL           | VALUE         | UNIT |  |
| OUTPUT (DETECTOR)            |                                      |                  |               |      |  |
| Collector emitter voltage    |                                      | V <sub>CEO</sub> | 70            | V    |  |
| Emitter collector voltage    |                                      | V <sub>ECO</sub> | 5             | V    |  |
| Collector current            |                                      | I <sub>C</sub>   | 100           | mA   |  |
| Power dissipation            | T <sub>amb</sub> ≤ 55 °C             | P <sub>V</sub>   | 100           | mW   |  |
| Junction temperature         |                                      | T <sub>j</sub>   | 100           | °C   |  |
| SENSOR                       |                                      |                  |               |      |  |
| Total power dissipation      | T <sub>amb</sub> ≤ 25 °C             | P <sub>tot</sub> | 200           | mW   |  |
| Ambient temperature range    |                                      | T <sub>amb</sub> | - 25 to + 85  | °C   |  |
| Storage temperature range    |                                      | T <sub>stg</sub> | - 25 to + 100 | °C   |  |
| Soldering temperature        | 2 mm from case, $t \le 10 \text{ s}$ | T <sub>sd</sub>  | 260           | °C   |  |

#### Note

#### **ABSOLUTE MAXIMUM RATINGS**

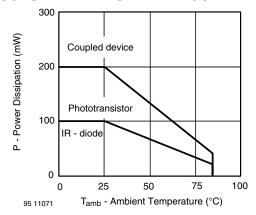


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (1)            |   |                                   |      |      |      |       |
|--------------------------------------|---|-----------------------------------|------|------|------|-------|
| PARAMETER                            | TEST CONDITION  | SYMBOL                            | MIN. | TYP. | MAX. | UNIT  |
| INPUT (EMITTER)                      |   |                                   |      |      |      |       |
| Forward voltage                      | I <sub>F</sub> = 60 mA  | V <sub>F</sub>                    |      | 1.25 | 1.5  | V     |
| Junction capacitance                 | $V_R = 0 V, f = 1 MHz$  | C <sub>j</sub>                    |      | 17   |      | pF    |
| Radiant intensity                    | $I_F = 60 \text{ mA}, t_p = 20 \text{ ms}$                    | I <sub>e</sub>                    |      |      | 21   | mW/sr |
| Peak wavelength                      | I <sub>F</sub> = 100 mA                                       | λ <sub>P</sub>                    | 940  |      |      | nm    |
| Virtual source diameter              | Method: 63 % encircled energy                                 | d                                 |      | 2.1  |      | mm    |
| OUTPUT (DETECTOR)                    |   |                                   |      |      |      |       |
| Collector emitter voltage            | I <sub>C</sub> = 1 mA   | V <sub>CEO</sub>                  | 70   |      |      | V     |
| Emitter collector voltage            | I <sub>e</sub> = 100 μA                                       | V <sub>ECO</sub>                  | 7    |      |      | V     |
| Collector dark current               | $V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}, E = 0 \text{ Ix}$  | I <sub>CEO</sub>                  |      | 10   | 200  | nA    |
| SENSOR                               |   |                                   |      |      |      |       |
| Collector current                    | V <sub>CE</sub> = 5 V, I <sub>F</sub> = 10 mA,<br>D = 12 mm   | I <sub>C</sub> <sup>(2) (3)</sup> | 0.5  | 1    | 2.1  | mA    |
| Collector emitter saturation voltage | I <sub>F</sub> = 10 mA, I <sub>C</sub> = 0.1 mA,<br>D = 12 mm | V <sub>CEsat</sub> (2) (3)        |      |      | 0.4  | ٧     |

#### Note

- (1)  $T_{amb} = 25$  °C, unless otherwise specified
- (2) See figure 3
- (3) Test surface: mirror (Mfr. Spindler a. Hoyer, Part No. 340005)

 $<sup>^{(1)}</sup>$  T<sub>amb</sub> = 25 °C, unless otherwise specified



### Reflective Optical Sensor with Transistor Output

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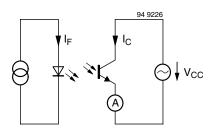


Fig. 2 - Test Circuit

# Flat mirror d = working distance $\emptyset$ = 22.5 mm rem. 2 D = distance 12 ± 0.2 mm

Fig. 3 - Test Circuit

#### **BASIC CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

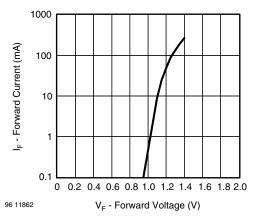


Fig. 4 - Forward Current vs. Forward Voltage

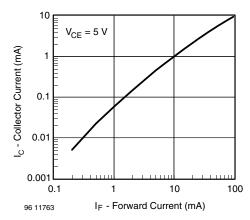


Fig. 6 - Collector Current vs. Forward Current

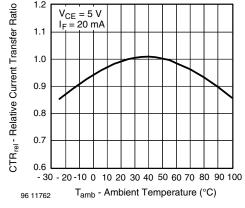


Fig. 5 - Relative Current Transfer Ratio vs. Ambient Temperature

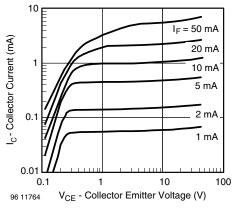


Fig. 7 - Collector Emitter Saturation Voltage vs. Collector Current

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## Reflective Optical Sensor with Transistor Output



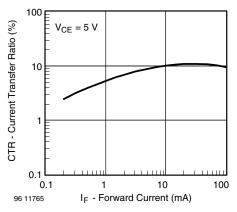


Fig. 8 - Current Transfer Ratio vs. Forward Current

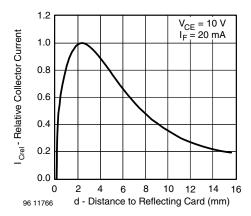
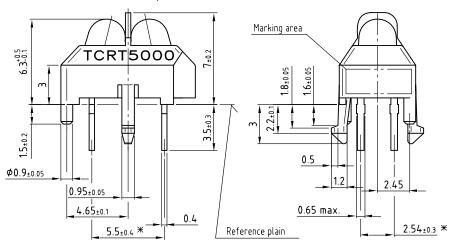
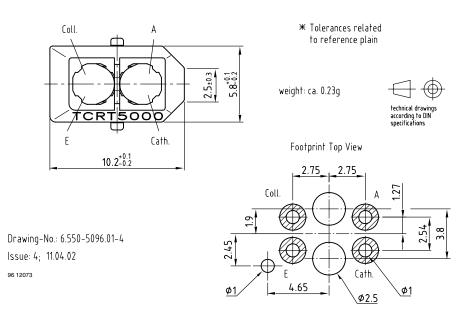


Fig. 9 - Relative Collector Current vs. Distance

#### **PACKAGE DIMENSIONS** in millimeters, **TCRT5000**



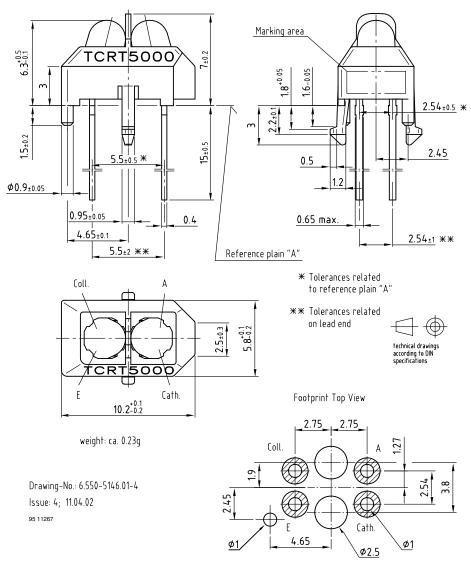




## Reflective Optical Sensor with Transistor Output

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## PACKAGE DIMENSIONS in millimeters, TCRT5000L

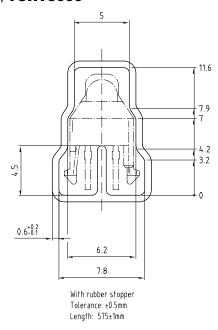


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## Reflective Optical Sensor with Transistor Output

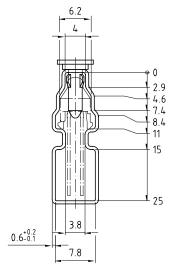


#### **TUBE DIMENSIONS** in millimeters, **TCRT5000**



Drawing-No.: 9.700-5139.01-4 Issue: 1; 10.05.00

#### **TUBE DIMENSIONS** in millimeters, **TCRT5000L**



With stopper pins Tolerance: ±0.5mm Length: 575±1mm

Drawing-No.: 9.700-5178.01-4 Issue: 1; 25.02.00 20299

# **Legal Disclaimer Notice**



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